BUY69A

## HIGH VOLTAGE NPN SILICON TRANSISTOR

- STM PREFERRED SALESTYPE
- NPN TRANSISTOR
- HIGH VOLTAGE CAPABILITY
- HIGH CURRENT CAPABILITY
- FAST SWITCHING SPEED
- HIGH POWER TO-3 PACKAGE


## APPLICATIONS:

- HORIZONTAL DEFLECTION FOR COLOUR TV
- SWITCHING REGULATORS


## DESCRIPTION

The BUY69A is a silicon multiepitaxial mesa NPN transistor in Jedec TO-3 metal case. It is intended for horizontal deflection output stage of CTV receivers and high voltage, fast switching and industrial applications.


INTERNAL SCHEMATIC DIAGRAM



## BUY69A

THERMAL DATA

| R $_{\text {thj-case }}$ | Thermal Resistance Junction-case | Max | 1.75 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :--- | :--- | :--- | :--- | :--- |

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\text {case }}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Ices | Collector Cut-off Current ( $\mathrm{V}_{\mathrm{BE}}=0$ ) | $\mathrm{V}_{\text {CE }}=1000 \mathrm{~V}$ |  |  | 1 | mA |
| $I_{\text {ebo }}$ | Emitter Cut-off Current $\left(I_{C}=0\right)$ | $\mathrm{V}_{\text {EB }}=8 \mathrm{~V}$ |  |  | 1 | mA |
| $\mathrm{V}_{\text {CEO }}$ (sus) | Collector-Emitter Sustaining Voltage | $\mathrm{Ic}=100 \mathrm{~mA}$ | 1000 |  |  | V |
| $\mathrm{V}_{\mathrm{CE} \text { (sat)* }}$ | Collector-Emitter Saturation Voltage | $\mathrm{I}_{\mathrm{C}}=8 \mathrm{~A} \quad \mathrm{I}_{\mathrm{B}}=2.5 \mathrm{~A}$ |  |  | 3.3 | V |
| $V_{\text {be(sat)* }}$ | Base-Emitter Saturation Voltage | $\mathrm{IC}=8 \mathrm{~A} \quad \mathrm{IB}=2.5 \mathrm{~A}$ |  |  | 2.2 | V |
| $\mathrm{hFE}^{*}$ | DC Current Gain | $\mathrm{I}_{\mathrm{C}}=2.5 \mathrm{~A} \quad \mathrm{~V}_{\text {CE }}=10 \mathrm{~V}$ | 15 |  |  |  |
| $\mathrm{f}_{\mathrm{T}}$ | Transition Frequency | $\mathrm{I}_{\mathrm{C}}=0.5 \mathrm{~A} \quad \mathrm{~V}_{\text {CE }}=10 \mathrm{~V}$ |  | 10 |  | MHz |
| $\mathrm{I}_{\mathrm{s} / \mathrm{b}}{ }^{* *}$ | Second Breakdown Collector Current | $\mathrm{V}_{\text {CE }}=25 \mathrm{~V}$ | 4 |  |  | A |
| ton | Turn on Time | $\begin{array}{ll} \hline \mathrm{IC}=5 \mathrm{~A} & \mathrm{~V}_{\mathrm{CE}}=250 \mathrm{~V} \\ \mathrm{I}_{\mathrm{B} 1}=1 \mathrm{~A} & \end{array}$ |  | 0.2 |  | $\mu \mathrm{S}$ |
| $\begin{aligned} & \mathrm{t}_{\mathrm{s}} \\ & \mathrm{t}_{\mathrm{s}} \end{aligned}$ | Storage Time Fall Time | $\begin{array}{ll} \hline \mathrm{I}_{\mathrm{C}}=5 \mathrm{~A} & \mathrm{~V}_{\mathrm{CE}}=250 \mathrm{~V} \\ \mathrm{I}_{\mathrm{B} 1}=-\mathrm{I}_{\mathrm{B} 2}=1 \mathrm{~A} & \end{array}$ |  |  | $\begin{aligned} & 1.7 \\ & 0.3 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{~s} \end{aligned}$ |
| $t_{f}$ | Fall Time | $\begin{array}{ll} \mathrm{I}_{\mathrm{C}}=8 \mathrm{~A} & \mathrm{~V} \mathrm{CE}=40 \mathrm{~V} \\ \mathrm{I}_{\mathrm{B} 1}=-\mathrm{I}_{\mathrm{B} 2}=2.5 \mathrm{~A} & \end{array}$ |  |  | 1 | $\mu \mathrm{s}$ |

* Pulsed: Pulse duration = $300 \mu \mathrm{~s}$, duty cycle 1.5 \%
** Pulsed: 1s, non repetitive pulse.
For characteristics curves see the BUW34/5/6 series.

TO-3 MECHANICAL DATA

| DIM. | mm |  |  |  | inch |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 11.00 |  | 13.10 | 0.433 |  | 0.516 |
| B | 0.97 |  | 1.15 | 0.038 |  | 0.045 |
| C | 1.50 |  | 1.65 | 0.059 |  | 0.065 |
| D | 8.32 |  | 8.92 | 0.327 |  | 0.351 |
| E | 19.00 |  | 20.00 | 0.748 |  | 0.787 |
| G | 10.70 |  | 11.10 | 0.421 |  | 0.437 |
| N | 16.50 |  | 17.20 | 0.649 |  | 0.677 |
| P | 25.00 |  | 26.00 | 0.984 |  | 1.023 |
| R | 4.00 |  | 4.09 | 0.157 |  | 0.161 |
| U | 38.50 |  | 39.30 | 1.515 |  | 1.547 |
|  |  |  | 30.30 | 1.187 |  | 1.193 |



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